PCI	N Nu	mber:	20240423000.1									PCN D	ate:	April 23, 2024	
Titl	le:	Qualifica	ation	of Cu	as an	alter	nate bo	ond wi	re for sele	ct de	evio	ces			
Cus	stom	er Conta	ct:	Chan	ge Mai	nage	ment 1	「eam	Dept:	Qua	alit	y Servi	ices		
Pro	pose	ed 1 st Shi	ip Da	ate:	July 2	2, 20	024				Requests May 23, 2024*				
*Sa	ampl	e reques	sts re	eceive	d afte	r Ma	y 23,	2024	will not I	oe si	upj	ported	l		
	Asse	embly Sit	e				Desig	jn 💮				Wafer Bump Material			
	Asse	embly Pro	cess				Data	Sheet				Wafei	r Bum	p Process	
	Assembly Materials						Part	numbe	r change			Wafei	r Fab S	Site	
	Mechanical Specification						Test Site					Wafei	r Fab I	Material	
	Packing/Shipping/Labeling						Test Process					Wafei	r Fab I	Process	

PCN Details

Description of Change:

This PCN is to inform of an alternative bond wire qualification for the devices in the product affected section as follows:

What	Current	Additional
Bond wire type, Diameter	Au, 0.96 mil	Cu, 0.8 mil

Reason for Change:

Continuity of supply.

- 1) To align with world technology trends and use wiring with enhanced mechanical and electrical properties
- 2) Maximize flexibility within our Assembly/Test production sites.
- 3) Cu is easier to obtain and stock

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474											
No Change	No Change	│	No Change											
Changes to produc	Changes to product identification resulting from this PCN:													

None

Product Affected:

TPS92691PWP	TPS92692PWP	TPS92692PWPT
TPS92691PWPR	TPS92692PWPR	AMC3336DWER

Automotive Qualification Summary

(As per AEC-Q100 Rev. J and JEDEC Guidelines) Approve Date 31-March-2024

Product Attributes

Attributes	Qual Device:	QBS Process Reference:	QBS Package Reference:	QBS Package Reference:	QBS Product Reference:
Attributes	TPS92691QPWPRQ1	S0704038C0PLPR	TPS61175QPWPRQ1	SN2HA08CQPWPRQ1	TPS92691QPWPQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 125	-40 to 125
Product Function	Power Management	Power Management	Power Management	Power Management	Power Management
Wafer Fab Supplier	RFAB	RFAB	мн8	RFAB	RFAB
Assembly Site	TAI	TAI	TAI	TAI	TAI
Package Group	TSSOP	QFP	TSSOP	TSSOP	TSSOP
Package Designator	PWP	PLP	PWP	PWP	PWP
Pin Count	16	128	14	24	16

QBS: Qual By Similarity
Qual Device TPS92691QPWPRQ1 is qualified at MSL3 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

	De	ıta ı	υisμ	iayeu as	. Nulli	Jei oi	1015 / 1016	ai sample	Size / Tota	ii ialleu	
#	Test Spec	Min Lot	SS /	Test Name	Condition	Duration	Qual Device:	QBS Process Reference:	QBS Package Reference:	QBS Package Reference:	QBS Product Reference:
		Qty					TPS92691QPWPRQ1	S0704038C0PLPR	TPS61175QPWPRQ1	SN2HA08CQPWPRQ1	TPS92691QPWPQ1
A - Acc	elerated Enviror	nment S	tress Te	sts							
A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL3 260C	-	1/AII/0	3/Ali/0	3/AII/0	3/All/0	1/All/0
A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	3/231/0	-	3/231/0	1/77/0
А3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours		3/231/0	•	3/231/0	1/77/0
А3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	-	3/231/0	-	-
A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-55C/150C	1000 Cycles	1/77/0	Ē.	To the second	-	i.
A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	-	3/236/0	3/231/0	3/231/0	1/77/0
A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	-	1/5/0	1/5/0	-	1/5/0
A5	JEDEC JESD22- A105	1	45	PTC	-40/125C	1000 Cycles	-	3/45/0	-	1/45/0	
A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	1/45/0	-	1/45/0	3/135/0	
A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	500 Hours	-	3/45/0	-	-	-
B - Acc	elerated Lifetime	Simula	tion Tes	ts			is:		is a		
B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours		3/231/0	-	1-	-
B1	JEDEC JESD22- A108	3	77	Life Test	150C	300 Hours	-	-	-	-	3/231/0
	A - Acco A1 A2 A3 A4 A4 A4 A5 A6 B - Acco B1	# Test Spec A - Accelerated Environ A1 JEDEC J- STD-020 A113 A2 JEDEC JESD22- A113 A3 JEDEC JESD22- A102/JEDEC JESD22- A102/JEDEC JESD22- A102/JEDEC JESD22- A104 A104 A104 Appendix 3 A4 MIL-STD883 A4 MIL-STD883 A4 MIL-STD883 A5 JEDEC JESD22- A103 A104 A104 A104 A104 A104 A104 A104 A104	# Test Spec Min	# Test Spec Min Lot Qty Lot A - Accelerated Environment Stress Test A1	# Test Spec Min	# Test Spec Min SS / Lot Test Name Condition A - Accelerated Environment Stress Tests A1 JEDEC J-STD-020 3 77 Preconditioning MSL3 260C A2 JEDEC J-STD-020 3 77 Biased HAST 130C/85%RH A2 JEDEC J-SSD22- A113 77 Autoclave 121C/15psig A3 JEDEC J-SSD22- A102/JEDEC 3 77 Autoclave 121C/15psig A4 JEDEC J-SSD22- A118 77 Unbiased HAST 130C/85%RH A5 JEDEC J-SSD22- A118 77 Temperature -55C/150C A6 JEDEC J-SSD22- A104 A104 and Appendix 3 77 Temperature -55C/150C A4 MIL-STD883 77 Temperature -65C/150C A5 JEDEC J-SSD22- A104 A105 A105 A105 A6 JEDEC J-SSD22- A105 A105 A105 A6 JEDEC J-SSD22- A105 A105 A105 A6 JEDEC J-SSD22- A106 A105 A105 A6 JEDEC J-SSD22- A106 A105 A105 A6 JEDEC J-SSD22- A106 A105 A105 A7 Life Test A150 A105 B7 Accelerated Lifetime Simulation Tests B1 JEDEC J-SSD22- A108 A77 Life Test 150C B1 JEDEC J-SSD22- A108 A77 Life Test 1	# Test Spec Min	# Test Spec Min Lot Qty SS / Lot Test Name Condition Duration Qual Device: TPS92591QPMPRQ1 A - Accelerated Environment Stress Tests A1	Test Spec	Test Spec	Second

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: <u>TPS92691QPWPRQ1</u>	QBS Process Reference: S0704038C0PLPR	QBS Package Reference: <u>TPS61175QPWPRQ1</u>	QBS Package Reference: SN2HA08CQPWPRQ1	QBS Product Reference: TPS92691QPWPQ1
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	150C	408 Hours	-	-	-	3/231/0	-
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	-		-
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	150C	24 Hours	-	-	-	3/2400/0	i.
EDR	В3	AEC Q100- 005	1	77	NVM Endurance, Data Retention, and Op Life	Per QSS-009- 018	1 Step	-	-	-	3/231/0	-
Test Group	C - Paci	age Assembly	Integrity	Tests					70 2			
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	3/90/0	3/90/0	1/30/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	3/90/0	3/90/0	1/30/0
SD	C3	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	1/15/0	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions	Cpk>1.67	-	-	-2	3/30/0	3/30/0	1/10/0
Test Group	D - Die F	abrication Relia	ability Te	sts	V0 2							
ЕМ	D1	JESD61		÷	Electromigration	ō	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35			Time Dependent Dielectric Breakdown		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
вті	D4	_	_	2	Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	trical Verificatio	n Tests									
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	-	1/3/0	-	3/9/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	-	1/3/0	-	3/9/0	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	-	1/6/0	-	1/6/0	1/3/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-	3/90/0	-	3/90/0	3/90/0
		-										

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7 eV: 150 C/1 k Hours, and 170 C/420 Hours

The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

 ${\sf Room/Hot: THB\ /\ HAST,\ TC\ /\ PTC,\ HTSL,\ ELFR,\ ESD\ \&\ LU}$

Room: AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Qualification ReportAutomotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) Approve Date 07-September -2023

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

			Data	Disp	played as:	Number	of lo	ts / T	otal sam	ole si	ze / Id	otal fa	iled			
Туре	#	Test Spec	Min Lot Qty	SS		e Condit	ion D	uration	Qual Devi AMC3311QDV	ce: <u>WERQ1</u>	QBS Pr Refer ISO7741	ence:	QBS Pro Refere AMC1305M25	nce:	QBS Po Refero AMC131M03	ence:
Test Group	A - Acc	elerated Enviro	onment S	Stress T	ests											
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Precondition	ing MSL3 26	oc -		No Fails		-		-		No Fails	
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	110C/85		64 lours	1/77/0		-				3/231/0	
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HA	AST 110C/85		64 lours	3/231/0				-		3/231/0	
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150		00 cycles	3/231/0		-				3/231/0	
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond F	Pull -			1/5/0		-		-			
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C		00 lours	1/45/0		-		-		3/135/0	
Test Group	B - Acc	elerated Lifetin	ne Simul	ation Te	ests											
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	125C		000 lours			3/231/0				-	
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	150C		08 lours	-		-		3/231/0			
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	125C		8 lours			3/2400/0					
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C		4 lours					3/2400/0		-	
Test Group	C - Pac	kage Assembly	/ Integrit	y Tests												
WBS	C1	AEC Q100- 001	1		Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/	О	-		-				
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/	О			-				
SD	СЗ	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage				-				1/15/0		
SD	C3	JEDEC J- STD-002	1		PB-Free Solderability	>95% Lead Coverage				-		-		1/15/0		
PD	C4	JEDEC JESD22- B100 and B108	1		Physical Dimensions	Cpk>1.67	-	3/30/	o			-				

Test Gro	up D - Die	Fabrication Rel	iability 1	ests .					W.		
EM	D1	JESD61	-		Electromigration			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-		Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28			Hot Carrier Injection	-		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4				Negative Bias Temperature Instability	-		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5		23	2	Stress Migration			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Gro	up E - Elec	ctrical Verification	on Tests		- 1				2010		000
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0	-		-
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-		
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	-	-	
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90/0	-	-	

QBS: Qual By Similarity

Qual Device AMC3311QDWERQ1 is qualified at MSL3 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7 eV: 150 C/1 k Hours, and 170 C/420 Hours

The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C

Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Qualification Report

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) Approve Date 26-September -2023

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

					Data Di	Spiaye	ı as.	Mullipel 0	1 1013 / 101	ai sairipid	e size / Tot	ai iaiicu		
Туре		Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration	Qual Device: AMC33330QDWERQ1	QBS Process Reference: INA215AQDCKRQ1	QBS Process Reference: ISO7741FQDWQ1	QBS Product Reference: AMC3301QDWERQ1	QBS Package Reference: ISOW7841FQDWEQ1	QBS Package Reference: TPSi3050QDWZRQ1	QBS Package Reference: UCC12051QDVERQ1
Test Group A	A - Acce	lerated Environ	ment St	ress Tes	its									
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL3 260C		3/0/0		-	3/0/0	-	3/0/0	3/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	110C/85%RH	264 Hours		-	-	-	-	3/231/0	3/231/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	-		-	3/231/0	-		-
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	110C/85%RH	264 Hours	1/20/0	-	-	1/77/0	-	3/231/0	-
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	-			3/231/11	-	-	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-55C/150C	1000 Cycles			-			3/231/0	
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	1/20/0	-	-	3/231/0	-		3/231/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull		-	-		-	3/15/0	-	1/5/0	3/15/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	170C	620 Hours		-		3/231/0	-		
Test Group I	B - Acce	lerated Lifetime	e Simula	tion Test	ts									
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	-	3/231/0	3/231/0	-	-	-	-
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	150C	408 Hours	-	-		3/231/3 ²	-	-	
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	3/2400/0	-	-	-	-
Test Group (C - Pack	age Assembly	Integrity	Tests										
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	3/90/0	3/90/0	-	
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	3/90/0	3/90/0	-	-
SD	C3	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage				-	1/15/0	1/15/0	-	
SD	С3	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-			-	1/15/0	1/15/0	-	
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions	Cpk>1.67	-	1/10/0	-	-	-	2/20/0	-	
Test Group I	D - Die F	abrication Relia	ability Te	sts										
ЕМ	D1	JESD61			Electromigration			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements

Туре	#	Test Spec	Min Lot	SS/	Test Name	Condition	Duration	Qual Device: AMC3330QDWERQ1	QBS Process Reference:	QBS Process Reference:	QBS Product Reference:	QBS Package Reference:	QBS Package Reference:	QBS Package Reference:
			Qty					Amossaggwengs	INA215AQDCKRQ1	ISO7741FQDWQ1	AMC3301QDWERQ1	ISOW7841FQDWEQ1	TPSI3050QDWZRQ1	UCC12051QDVERQ1
TDDB	D2	JESD35			Time Dependent Dielectric Breakdown		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28			Hot Carrier Injection			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4				Negative Bias Temperature Instability			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5				Stress Migration			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verificatio	n Tests											
ESD	E2	AEC Q100- 002	1	3	ESD HBM		3500 Volts	-	-	-	3/9/0	-		-
ESD	E3	AEC Q100- 011	1	3	ESD CDM		1500 Volts		-	-	3/9/0			
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-		-	-	3/18/0			
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold		-	-		3/90/0	-		

QBS: Qual By Similarity

Qual Device AMC3330QDWERQ1 is qualified at MSL3 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

For questions regarding this notice, e-mails can be sent to Change Management team or your local Field Sales Representative.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for,

and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.